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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	180MHz
Connectivity	CANbus, EBI/EMI, Ethernet, I <sup>2</sup> C, IrDA, LINbus, SPI, UART/USART, USB OTG
Peripherals	Brown-out Detect/Reset, DMA, I <sup>2</sup> S, POR, PWM, WDT
Number of I/O	130
Program Memory Size	1MB (1M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	256K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.6V
Data Converters	A/D 24x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	169-UFBGA
Supplier Device Package	169-UFBGA (7x7)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/stmicroelectronics/stm32f427agh6">https://www.e-xfl.com/product-detail/stmicroelectronics/stm32f427agh6</a>

## 2 Description

The STM32F427xx and STM32F429xx devices are based on the high-performance ARM® Cortex®-M4 32-bit RISC core operating at a frequency of up to 180 MHz. The Cortex-M4 core features a Floating point unit (FPU) single precision which supports all ARM® single-precision data-processing instructions and data types. It also implements a full set of DSP instructions and a memory protection unit (MPU) which enhances application security.

The STM32F427xx and STM32F429xx devices incorporate high-speed embedded memories (Flash memory up to 2 Mbyte, up to 256 kbytes of SRAM), up to 4 Kbytes of backup SRAM, and an extensive range of enhanced I/Os and peripherals connected to two APB buses, two AHB buses and a 32-bit multi-AHB bus matrix.

All devices offer three 12-bit ADCs, two DACs, a low-power RTC, twelve general-purpose 16-bit timers including two PWM timers for motor control, two general-purpose 32-bit timers. They also feature standard and advanced communication interfaces.

- Up to three I<sup>2</sup>Cs
- Six SPIs, two I<sup>2</sup>Ss full duplex. To achieve audio class accuracy, the I<sup>2</sup>S peripherals can be clocked via a dedicated internal audio PLL or via an external clock to allow synchronization.
- Four USARTs plus four UARTs
- An USB OTG full-speed and a USB OTG high-speed with full-speed capability (with the ULPI),
- Two CANs
- One SAI serial audio interface
- An SDIO/MMC interface
- Ethernet and camera interface
- LCD-TFT display controller
- Chrom-ART Accelerator™.

Advanced peripherals include an SDIO, a flexible memory control (FMC) interface, a camera interface for CMOS sensors. Refer to [Table 2: STM32F427xx and STM32F429xx features and peripheral counts](#) for the list of peripherals available on each part number.

The STM32F427xx and STM32F429xx devices operates in the –40 to +105 °C temperature range from a 1.7 to 3.6 V power supply.

The supply voltage can drop to 1.7 V with the use of an external power supply supervisor (refer to [Section 3.17.2: Internal reset OFF](#)). A comprehensive set of power-saving mode allows the design of low-power applications.

The STM32F427xx and STM32F429xx devices offer devices in 8 packages ranging from 100 pins to 216 pins. The set of included peripherals changes with the device chosen.

FIFOS with 3 stages and 28 shared scalable filter banks (all of them can be used even if one CAN is used). 256 bytes of SRAM are allocated for each CAN.

### 3.33 Universal serial bus on-the-go full-speed (OTG\_FS)

The devices embed an USB OTG full-speed device/host/OTG peripheral with integrated transceivers. The USB OTG FS peripheral is compliant with the USB 2.0 specification and with the OTG 1.0 specification. It has software-configurable endpoint setting and supports suspend/resume. The USB OTG full-speed controller requires a dedicated 48 MHz clock that is generated by a PLL connected to the HSE oscillator. The major features are:

- Combined Rx and Tx FIFO size of  $320 \times 35$  bits with dynamic FIFO sizing
- Supports the session request protocol (SRP) and host negotiation protocol (HNP)
- 4 bidirectional endpoints
- 8 host channels with periodic OUT support
- HNP/SNP/IP inside (no need for any external resistor)
- For OTG/Host modes, a power switch is needed in case bus-powered devices are connected

### 3.34 Universal serial bus on-the-go high-speed (OTG\_HS)

The devices embed a USB OTG high-speed (up to 480 Mb/s) device/host/OTG peripheral. The USB OTG HS supports both full-speed and high-speed operations. It integrates the transceivers for full-speed operation (12 MB/s) and features a UTMI low-pin interface (ULPI) for high-speed operation (480 MB/s). When using the USB OTG HS in HS mode, an external PHY device connected to the ULPI is required.

The USB OTG HS peripheral is compliant with the USB 2.0 specification and with the OTG 1.0 specification. It has software-configurable endpoint setting and supports suspend/resume. The USB OTG full-speed controller requires a dedicated 48 MHz clock that is generated by a PLL connected to the HSE oscillator.

The major features are:

- Combined Rx and Tx FIFO size of  $1 \text{ Kbit} \times 35$  with dynamic FIFO sizing
- Supports the session request protocol (SRP) and host negotiation protocol (HNP)
- 6 bidirectional endpoints
- 12 host channels with periodic OUT support
- Internal FS OTG PHY support
- External HS or HS OTG operation supporting ULPI in SDR mode. The OTG PHY is connected to the microcontroller ULPI port through 12 signals. It can be clocked using the 60 MHz output.
- Internal USB DMA
- HNP/SNP/IP inside (no need for any external resistor)
- for OTG/Host modes, a power switch is needed in case bus-powered devices are connected

### 3.42 Embedded Trace Macrocell™

The ARM Embedded Trace Macrocell provides a greater visibility of the instruction and data flow inside the CPU core by streaming compressed data at a very high rate from the STM32F42x through a small number of ETM pins to an external hardware trace port analyzer (TPA) device. The TPA is connected to a host computer using USB, Ethernet, or any other high-speed channel. Real-time instruction and data flow activity can be recorded and then formatted for display on the host computer that runs the debugger software. TPA hardware is commercially available from common development tool vendors.

The Embedded Trace Macrocell operates with third party debugger software tools.

Table 11. FMC pin definition (continued)

Pin name	CF	NOR/PSRAM/ SRAM	NOR/PSRAM Mux	NAND16	SDRAM
PF6	NIORD				
PF7	NREG				
PF8	NIOWR				
PF9	CD				
PF10	INTR				
PG6				INT2	
PG7				INT3	
PE0		NBL0	NBL0		NBL0
PE1		NBL1	NBL1		NBL1
PI4		NBL2			NBL2
PI5		NBL3			NBL3
PG8					SDCLK
PC0					SDNWE
PF11					SDNRAS
PG15					SDNCAS
PH2					SDCKE0
PH3					SDNE0
PH6					SDNE1
PH7					SDCKE1
PH5					SDNWE
PC2					SDNE0
PC3					SDCKE0
PB5					SDCKE1
PB6					SDNE1

Table 12. STM32F427xx and STM32F429xx alternate function mapping (continued)

Port		AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7	AF8	AF9	AF10	AF11	AF12	AF13	AF14	AF15
		SYS	TIM1/2	TIM3/4/5	TIM8/9/ 10/11	I2C1/ 2/3	SPI1/2/ 3/4/5/6	SPI2/3/ SAI1	SPI3/ USART1/ 2/3	USART6/ UART4/5/7 /8	CAN1/2/ TIM12/13/14 /LCD	OTG2_HS /OTG1_ FS	ETH	FMC/SDIO /OTG2_FS	DCMI	LCD	SYS
Port J	PJ8	-	-	-	-	-	-	-	-	-	-	-	-	-	-	LCD_G1	EVEN TOUT
	PJ9	-	-	-	-	-	-	-	-	-	-	-	-	-	-	LCD_G2	EVEN TOUT
	PJ10	-	-	-	-	-	-	-	-	-	-	-	-	-	-	LCD_G3	EVEN TOUT
	PJ11	-	-	-	-	-	-	-	-	-	-	-	-	-	-	LCD_G4	EVEN TOUT
	PJ12	-	-	-	-	-	-	-	-	-	-	-	-	-	-	LCD_B0	EVEN TOUT
	PJ13	-	-	-	-	-	-	-	-	-	-	-	-	-	-	LCD_B1	EVEN TOUT
	PJ14	-	-	-	-	-	-	-	-	-	-	-	-	-	-	LCD_B2	EVEN TOUT
	PJ15	-	-	-	-	-	-	-	-	-	-	-	-	-	-	LCD_B3	EVEN TOUT
Port K	PK0	-	-	-	-	-	-	-	-	-	-	-	-	-	-	LCD_G5	EVEN TOUT
	PK1	-	-	-	-	-	-	-	-	-	-	-	-	-	-	LCD_G6	EVEN TOUT
	PK2	-	-	-	-	-	-	-	-	-	-	-	-	-	-	LCD_G7	EVEN TOUT
	PK3	-	-	-	-	-	-	-	-	-	-	-	-	-	-	LCD_B4	EVEN TOUT
	PK4	-	-	-	-	-	-	-	-	-	-	-	-	-	-	LCD_B5	EVEN TOUT
	PK5	-	-	-	-	-	-	-	-	-	-	-	-	-	-	LCD_B6	EVEN TOUT
	PK6	-	-	-	-	-	-	-	-	-	-	-	-	-	-	LCD_B7	EVEN TOUT
	PK7	-	-	-	-	-	-	-	-	-	-	-	-	-	-	LCD_DE	EVEN TOUT

1. The DCMI\_VSYNC alternate function on PG9 is only available on silicon revision 3.

**Table 22. reset and power control block characteristics (continued)**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$I_{RUSH}^{(1)}$	InRush current on voltage regulator power-on (POR or wakeup from Standby)		-	160	200	mA
$E_{RUSH}^{(1)}$	InRush energy on voltage regulator power-on (POR or wakeup from Standby)	$V_{DD} = 1.7\text{ V}$ , $T_A = 105\text{ }^{\circ}\text{C}$ , $I_{RUSH} = 171\text{ mA}$ for $31\text{ }\mu\text{s}$	-	-	5.4	$\mu\text{C}$

1. Guaranteed by design.
2. The reset temporization is measured from the power-on (POR reset or wakeup from  $V_{BAT}$ ) to the instant when first instruction is read by the user application code.

### 6.3.6 Over-drive switching characteristics

When the over-drive mode switches from enabled to disabled or disabled to enabled, the system clock is stalled during the internal voltage set-up.

The over-drive switching characteristics are given in [Table 23](#). They are subject to general operating conditions for  $T_A$ .

**Table 23. Over-drive switching characteristics<sup>(1)</sup>**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Tod_swen	Over_drive switch enable time	HSI	-	45	-	$\mu\text{s}$
		HSE max for 4 MHz and min for 26 MHz	45	-	100	
		External HSE 50 MHz	-	40	-	
Tod_swdis	Over_drive switch disable time	HSI	-	20	-	
		HSE max for 4 MHz and min for 26 MHz.	20	-	80	
		External HSE 50 MHz	-	15	-	

1. Guaranteed by design.

**Table 24. Typical and maximum current consumption in Run mode, code with data processing running from Flash memory (ART accelerator enabled except prefetch) or RAM<sup>(1)</sup>**

Symbol	Parameter	Conditions	f <sub>HCLK</sub> (MHz)	Typ	Max <sup>(2)</sup>			Unit
					T <sub>A</sub> = 25 °C	T <sub>A</sub> = 85 °C	T <sub>A</sub> = 105 °C	
I <sub>DD</sub>	Supply current in RUN mode	All Peripherals enabled <sup>(3)(4)</sup>	180	98	104 <sup>(5)</sup>	123	141 <sup>(5)</sup>	mA
			168	89	98 <sup>(5)</sup>	116	133 <sup>(5)</sup>	
			150	75	84	100	115	
			144	72	81	96	112	
			120	54	58	72	85	
			90	43	45	56	66	
			60	29	30	38	45	
			30	16	20	34	46	
			25	13	16	30	43	
			16	11	13	27	39	
			8	5	9	23	36	
			4	4	8	21	34	
			2	2	7	20	33	
		All Peripherals disabled <sup>(3)</sup>	180	44	47 <sup>(5)</sup>	69	87 <sup>(5)</sup>	
			168	41	45 <sup>(5)</sup>	66	83 <sup>(5)</sup>	
			150	36	39	57	73	
			144	33	37	56	72	
			120	25	29	43	56	
			90	20	21	32	41	
			60	14	15	22	28	
			30	8	8	12	26	
			25	7	7	10	24	
			16	7	9	22	35	
			8	3	7	21	34	
			4	3	6	20	33	
			2	2	6	20	33	

1. Code and data processing running from SRAM1 using boot pins.
2. Guaranteed by characterization.
3. When analog peripheral blocks such as ADCs, DACs, HSE, LSE, HSI, or LSI are ON, an additional power consumption should be considered.
4. When the ADC is ON (ADON bit set in the ADC\_CR2 register), add an additional power consumption of 1.6 mA per ADC for the analog part.
5. Guaranteed by test in production.



**Table 31. Typical current consumption in Run mode, code with data processing running from Flash memory, regulator OFF (ART accelerator enabled except prefetch)<sup>(1)</sup>**

Symbol	Parameter	Conditions	f <sub>HCLK</sub> (MHz)	VDD=3.3 V		VDD=1.7 V		Unit
				I <sub>DD12</sub>	I <sub>DD</sub>	I <sub>DD12</sub>	I <sub>DD</sub>	
I <sub>DD12</sub> / I <sub>DD</sub>	Supply current in RUN mode from V <sub>12</sub> and V <sub>DD</sub> supply	All Peripherals enabled	168	77.8	1.3	76.8	1.0	mA
			150	70.8	1.3	69.8	1.0	
			144	64.5	1.3	63.6	1.0	
			120	49.9	1.2	49.3	0.9	
			90	39.2	1.3	38.7	1.0	
			60	27.2	1.2	26.8	0.9	
			30	15.6	1.2	15.4	0.9	
			25	13.6	1.2	13.5	0.9	
		All Peripherals disabled	168	38.2	1.3	37.0	1.0	
			150	34.6	1.3	33.4	1.0	
			144	31.3	1.3	30.3	1.0	
			120	24.0	1.2	23.2	0.9	
			90	18.1	1.4	18.0	1.0	
			60	12.9	1.2	12.5	0.9	
			30	7.2	1.2	6.9	0.9	
			25	6.3	1.2	6.1	0.9	

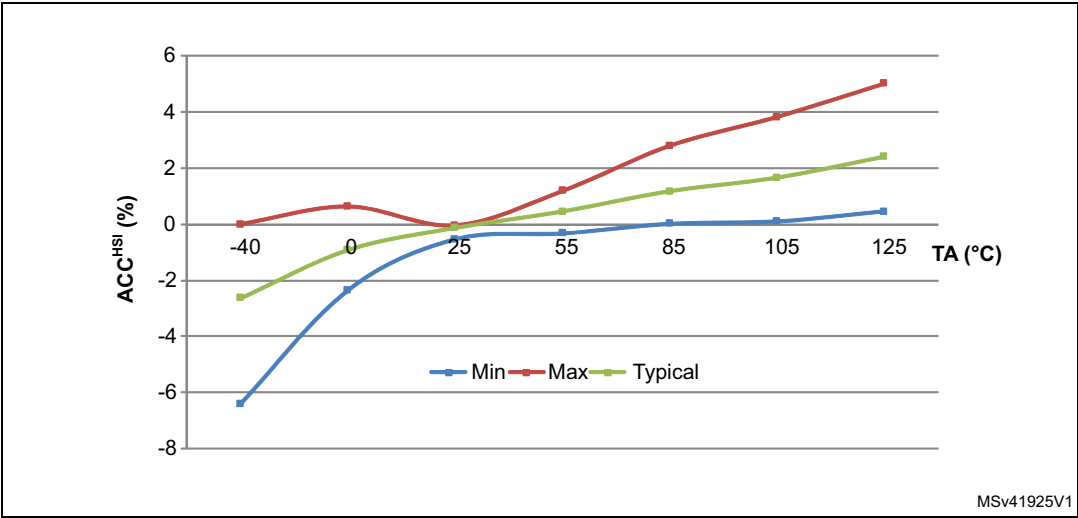
1. When peripherals are enabled, the power consumption corresponding to the analog part of the peripherals (such as ADC, or DAC) is not included.

Table 35. Peripheral current consumption (continued)

Peripheral		I <sub>DD</sub> ( Typ) <sup>(1)</sup>			Unit
		Scale 1	Scale 2	Scale 3	
APB2 (up to 90 MHz)	SDIO	8.11	8.75	7.83	μA/MHz
	TIM1	17.11	15.97	14.17	
	TIM8	17.33	16.11	14.33	
	TIM9	7.22	6.67	6.00	
	TIM10	4.56	4.31	3.83	
	TIM11	4.78	4.44	4.00	
	ADC1 <sup>(5)</sup>	4.67	4.31	3.83	
	ADC2 <sup>(5)</sup>	4.78	4.44	4.00	
	ADC3 <sup>(5)</sup>	4.56	4.17	3.67	
	SPI1	1.44	1.39	1.17	
	USART1	4.00	3.75	3.33	
	USART6	4.00	3.75	3.33	
	SPI4	1.44	1.39	1.17	
	SPI5	1.44	1.39	1.17	
	SPI6	1.44	1.39	1.17	
	SYSCFG	0.78	0.69	0.67	
	LCD_TFT	39.89	37.22	33.17	
	SAI1	3.78	3.47	3.17	

1. When the I/O compensation cell is ON, I<sub>DD</sub> typical value increases by 0.22 mA.
2. The BusMatrix is automatically active when at least one master is ON.
3. To enable an I2S peripheral, first set the I2SMOD bit and then the I2SE bit in the SPI\_I2SCFGR register.
4. When the DAC is ON and EN1/2 bits are set in DAC\_CR register, add an additional power consumption of 0.8 mA per DAC channel for the analog part.
5. When the ADC is ON (ADON bit set in the ADC\_CR2 register), add an additional power consumption of 1.6 mA per ADC for the analog part.

Figure 31. ACCHSI accuracy versus temperature



1. Guaranteed by characterization results.

### Low-speed internal (LSI) RC oscillator

Table 42. LSI oscillator characteristics <sup>(1)</sup>

Symbol	Parameter	Min	Typ	Max	Unit
$f_{LSI}^{(2)}$	Frequency	17	32	47	kHz
$t_{su(LSI)}^{(3)}$	LSI oscillator startup time	-	15	40	$\mu s$
$I_{DD(LSI)}^{(3)}$	LSI oscillator power consumption	-	0.4	0.6	$\mu A$

- $V_{DD} = 3 V$ ,  $T_A = -40$  to  $105^\circ C$  unless otherwise specified.
- Guaranteed by characterization results.
- Guaranteed by design.

Table 50. Flash memory endurance and data retention

Symbol	Parameter	Conditions	Value	Unit
			Min <sup>(1)</sup>	
$N_{\text{END}}$	Endurance	$T_A = -40$ to $+85$ °C (6 suffix versions) $T_A = -40$ to $+105$ °C (7 suffix versions)	10	kcycles
$t_{\text{RET}}$	Data retention	1 kcycle <sup>(2)</sup> at $T_A = 85$ °C	30	Years
		1 kcycle <sup>(2)</sup> at $T_A = 105$ °C	10	
		10 kcycles <sup>(2)</sup> at $T_A = 55$ °C	20	

1. Guaranteed by characterization results.

2. Cycling performed over the whole temperature range.

### 6.3.14 EMC characteristics

Susceptibility tests are performed on a sample basis during device characterization.

#### Functional EMS (electromagnetic susceptibility)

While a simple application is executed on the device (toggling 2 LEDs through I/O ports), the device is stressed by two electromagnetic events until a failure occurs. The failure is indicated by the LEDs:

- **Electrostatic discharge (ESD)** (positive and negative) is applied to all device pins until a functional disturbance occurs. This test is compliant with the IEC 61000-4-2 standard.
- **FTB:** A burst of fast transient voltage (positive and negative) is applied to  $V_{\text{DD}}$  and  $V_{\text{SS}}$  through a 100 pF capacitor, until a functional disturbance occurs. This test is compliant with the IEC 61000-4-4 standard.

A device reset allows normal operations to be resumed.

The test results are given in [Table 51](#). They are based on the EMS levels and classes defined in application note AN1709.

Table 51. EMS characteristics

Symbol	Parameter	Conditions	Level/Class
$V_{\text{FESD}}$	Voltage limits to be applied on any I/O pin to induce a functional disturbance	$V_{\text{DD}} = 3.3$ V, LQFP176, $T_A = +25$ °C, $f_{\text{HCLK}} = 168$ MHz, conforms to IEC 61000-4-2	2B
$V_{\text{EFTB}}$	Fast transient voltage burst limits to be applied through 100 pF on $V_{\text{DD}}$ and $V_{\text{SS}}$ pins to induce a functional disturbance	$V_{\text{DD}} = 3.3$ V, LQFP176, $T_A = +25$ °C, $f_{\text{HCLK}} = 168$ MHz, conforms to IEC 61000-4-2	4A

When the application is exposed to a noisy environment, it is recommended to avoid pin exposition to disturbances. The pins showing a middle range robustness are: PA0, PA1, PA2, PH2, PH3, PH4, PH5, PA3, PA4, PA5, PA6, PA7, PC4, and PC5.

As a consequence, it is recommended to add a serial resistor (1 k $\Omega$ ) located as close as possible to the MCU to the pins exposed to noise (connected to tracks longer than 50 mm on PCB).

### 6.3.17 I/O port characteristics

#### General input/output characteristics

Unless otherwise specified, the parameters given in [Table 56: I/O static characteristics](#) are derived from tests performed under the conditions summarized in [Table 17](#). All I/Os are CMOS and TTL compliant.

**Table 56. I/O static characteristics**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>IL</sub>	FT, TTa and NRST I/O input low level voltage	1.7 V≤V <sub>DD</sub> ≤3.6 V	-	-	0.35V <sub>DD</sub> (1) - 0.04	V
					0.3V <sub>DD</sub> (2)	
	BOOT0 I/O input low level voltage	1.75 V≤V <sub>DD</sub> ≤3.6 V, -40 °C≤T <sub>A</sub> ≤105 °C	-	-	0.1V <sub>DD</sub> +0.1(1)	
		1.7 V≤V <sub>DD</sub> ≤3.6 V, 0 °C≤T <sub>A</sub> ≤105 °C	-	-		
V <sub>IH</sub>	FT, TTa and NRST I/O input high level voltage(5)	1.7 V≤V <sub>DD</sub> ≤3.6 V	0.45V <sub>DD</sub> +0.3(1)	-	-	V
			0.7V <sub>DD</sub> (2)			
	BOOT0 I/O input high level voltage	1.75 V≤V <sub>DD</sub> ≤3.6 V, -40 °C≤T <sub>A</sub> ≤105 °C	0.17V <sub>DD</sub> +0.7(1)	-	-	
		1.7 V≤V <sub>DD</sub> ≤3.6 V, 0 °C≤T <sub>A</sub> ≤105 °C				
V <sub>HYS</sub>	FT, TTa and NRST I/O input hysteresis	1.7 V≤V <sub>DD</sub> ≤3.6 V	10%V <sub>DD</sub> (3)	-	-	V
	BOOT0 I/O input hysteresis	1.75 V≤V <sub>DD</sub> ≤3.6 V, -40 °C≤T <sub>A</sub> ≤105 °C	0.1	-	-	
		1.7 V≤V <sub>DD</sub> ≤3.6 V, 0 °C≤T <sub>A</sub> ≤105 °C				
I <sub>lkg</sub>	I/O input leakage current (4)	V <sub>SS</sub> ≤V <sub>IN</sub> ≤V <sub>DD</sub>	-	-	±1	μA
	I/O FT input leakage current (5)	V <sub>IN</sub> = 5 V	-	-	3	

Table 58. I/O AC characteristics<sup>(1)(2)</sup> (continued)

OSPEEDRy [1:0] bit value <sup>(1)</sup>	Symbol	Parameter	Conditions	Min	Typ	Max	Unit
11	$f_{\max(\text{IO})\text{out}}$	Maximum frequency <sup>(3)</sup>	$C_L = 30 \text{ pF}, V_{DD} \geq 2.7 \text{ V}$	-	-	100 <sup>(4)</sup>	MHz
			$C_L = 30 \text{ pF}, V_{DD} \geq 1.8 \text{ V}$	-	-	50	
			$C_L = 30 \text{ pF}, V_{DD} \geq 1.7 \text{ V}$	-	-	42.5	
			$C_L = 10 \text{ pF}, V_{DD} \geq 2.7 \text{ V}$	-	-	180 <sup>(4)</sup>	
			$C_L = 10 \text{ pF}, V_{DD} \geq 1.8 \text{ V}$	-	-	100	
			$C_L = 10 \text{ pF}, V_{DD} \geq 1.7 \text{ V}$	-	-	72.5	
	$t_{f(\text{IO})\text{out}}/$ $t_{r(\text{IO})\text{out}}$	Output high to low level fall time and output low to high level rise time	$C_L = 30 \text{ pF}, V_{DD} \geq 2.7 \text{ V}$	-	-	4	ns
			$C_L = 30 \text{ pF}, V_{DD} \geq 1.8 \text{ V}$	-	-	6	
			$C_L = 30 \text{ pF}, V_{DD} \geq 1.7 \text{ V}$	-	-	7	
			$C_L = 10 \text{ pF}, V_{DD} \geq 2.7 \text{ V}$	-	-	2.5	
			$C_L = 10 \text{ pF}, V_{DD} \geq 1.8 \text{ V}$	-	-	3.5	
			$C_L = 10 \text{ pF}, V_{DD} \geq 1.7 \text{ V}$	-	-	4	
-	$t_{\text{EXTI}pw}$	Pulse width of external signals detected by the EXTI controller	-	10	-	-	ns

1. Guaranteed by design.
2. The I/O speed is configured using the OSPEEDRy[1:0] bits. Refer to the STM32F4xx reference manual for a description of the GPIOx\_SPEEDR GPIO port output speed register.
3. The maximum frequency is defined in [Figure 36](#).
4. For maximum frequencies above 50 MHz and  $V_{DD} > 2.4 \text{ V}$ , the compensation cell should be used.

Figure 36. I/O AC characteristics definition

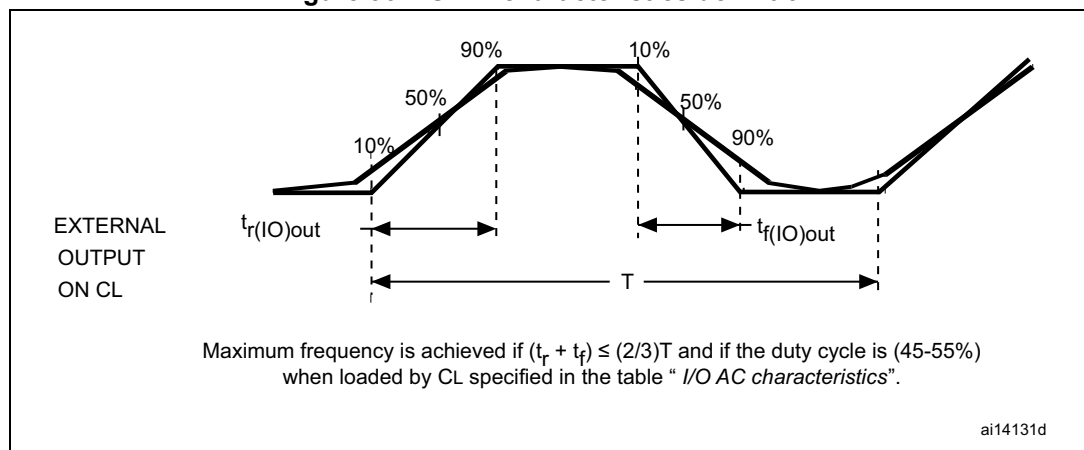


Table 62. SPI dynamic characteristics<sup>(1)</sup> (continued)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_{w(SCKH)}$	SCK high and low time	Master mode, SPI presc = 2, $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$	$T_{PCLK} - 0.5$	$T_{PCLK}$	$T_{PCLK} + 0.5$	ns
$t_{w(SCKL)}$		Master mode, SPI presc = 2, $1.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$	$T_{PCLK} - 2$	$T_{PCLK}$	$T_{PCLK} + 2$	
$t_{su(NSS)}$	NSS setup time	Slave mode, SPI presc = 2	$4T_{PCLK}$	-	-	
$t_{h(NSS)}$	NSS hold time	Slave mode, SPI presc = 2	$2T_{PCLK}$	-	-	
$t_{su(MI)}$	Data input setup time	Master mode	3	-	-	
$t_{su(SI)}$		Slave mode	0	-	-	
$t_{h(MI)}$	Data input hold time	Master mode	0.5	-	-	
$t_{h(SI)}$		Slave mode	2	-	-	
$t_{a(SO)}$	Data output access time	Slave mode, SPI presc = 2	0	-	$4T_{PCLK}$	
$t_{dis(SO)}$	Data output disable time	Slave mode, SPI1/4/5/6, $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$	0	-	8.5	
		Slave mode, SPI1/2/3/4/5/6 and $1.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$	0	-	16.5	
$t_{v(SO)}$ $t_{h(SO)}$	Data output valid/hold time	Slave mode (after enable edge), SPI1/4/5/6 and $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$	-	11	13	ns
		Slave mode (after enable edge), SPI2/3, $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$	-	14	15	
		Slave mode (after enable edge), SPI1/4/5/6, $1.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$	-	15.5	19	
		Slave mode (after enable edge), SPI2/3, $1.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$	-	15.5	17.5	
$t_{v(MO)}$	Data output valid time	Master mode (after enable edge), SPI1/4/5/6, $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$	-	-	2.5	
		Master mode (after enable edge), SPI1/2/3/4/5/6, $1.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$	-	-	4.5	
$t_{h(MO)}$	Data output hold time	Master mode (after enable edge)	0	-	-	

1. Guaranteed by characterization results.

2. Maximum frequency in Slave transmitter mode is determined by the sum of  $t_{v(SO)}$  and  $t_{su(MI)}$  which has to fit into SCK low or high phase preceding the SCK sampling edge. This value can be achieved when the SPI communicates with a master having  $t_{su(MI)} = 0$  while Duty(SCK) = 50%

Figure 76. LCD-TFT horizontal timing diagram

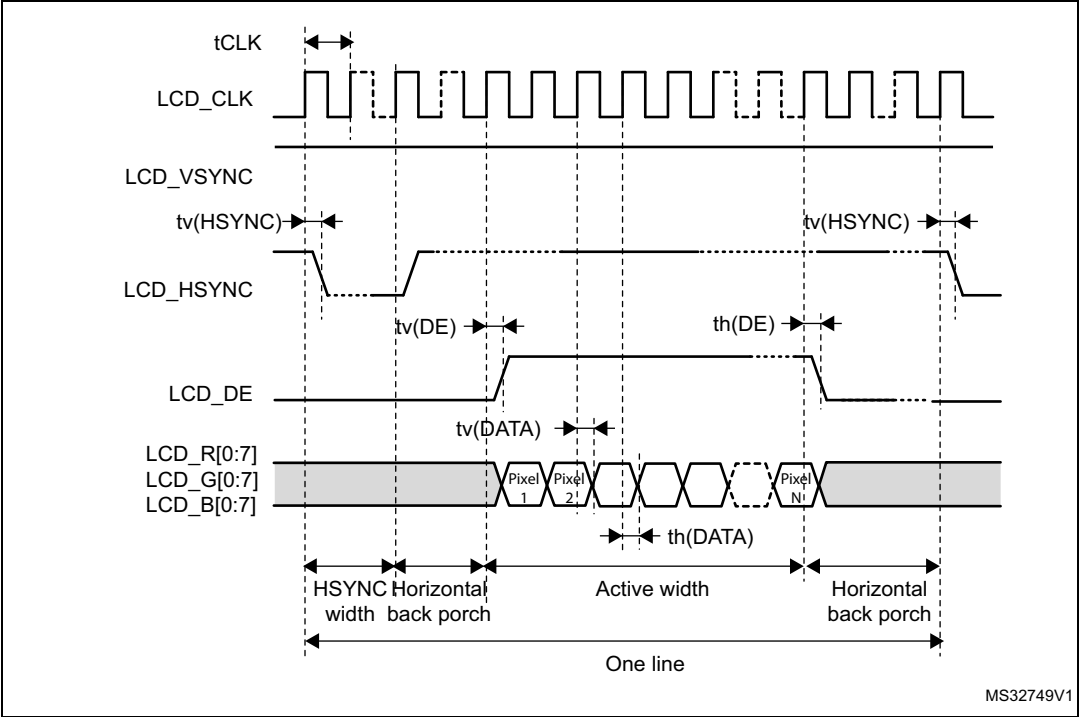
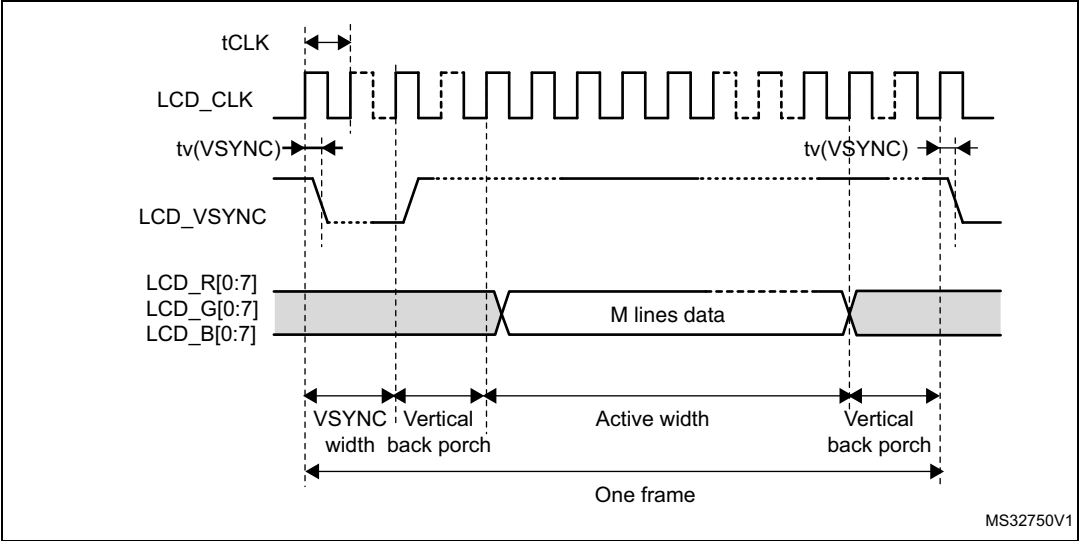


Figure 77. LCD-TFT vertical timing diagram



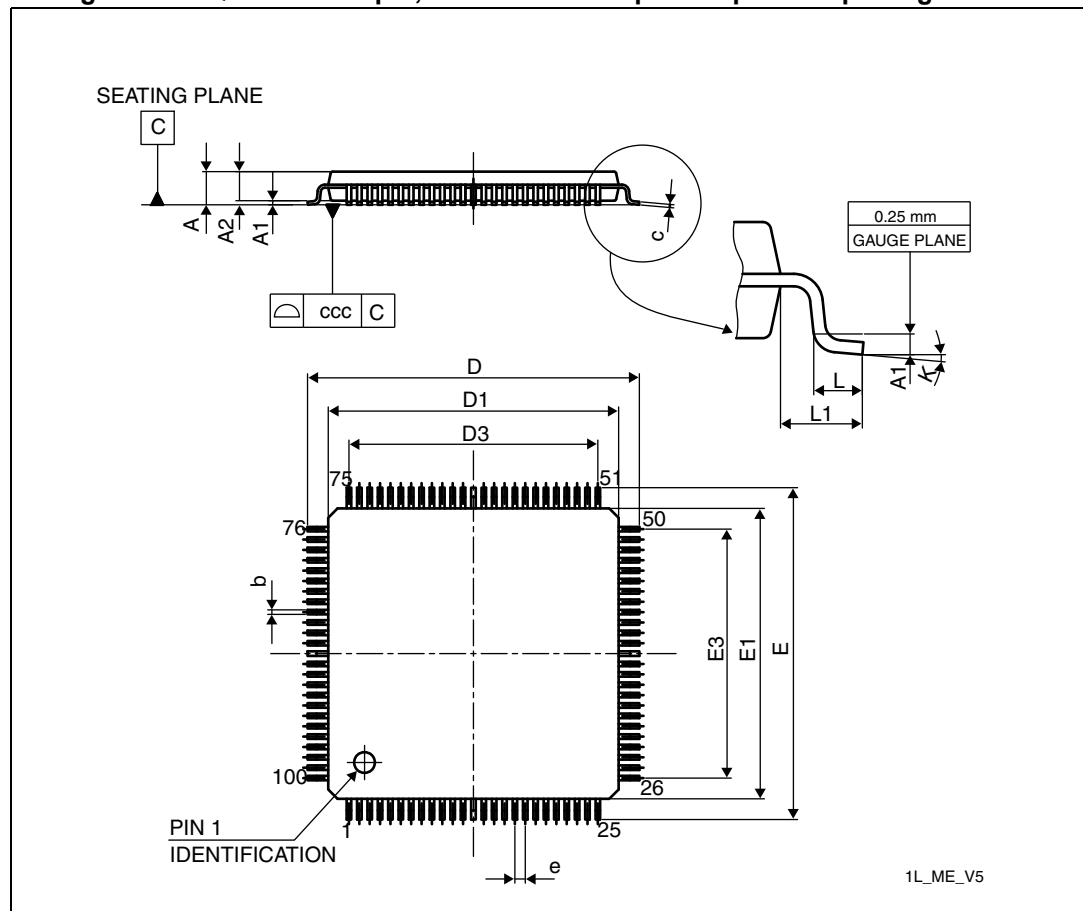


## 7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

### 7.1 LQFP100 package information

Figure 80. LQFP100 -100-pin, 14 x 14 mm low-profile quad flat package outline



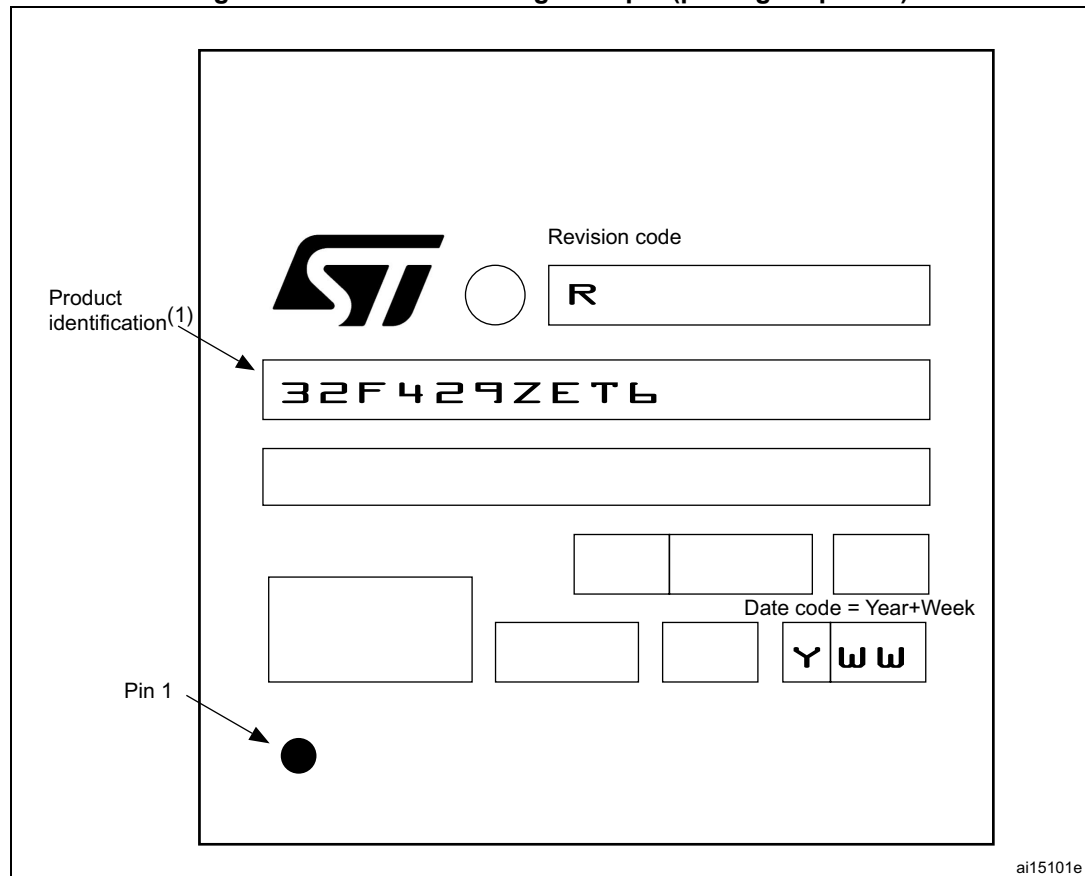
1. Drawing is not to scale.

### Device marking for LQFP144

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

Other optional marking or inset/upset marks, which depends assembly location, are not indicated below.

**Figure 88. LQFP144 marking example (package top view)**



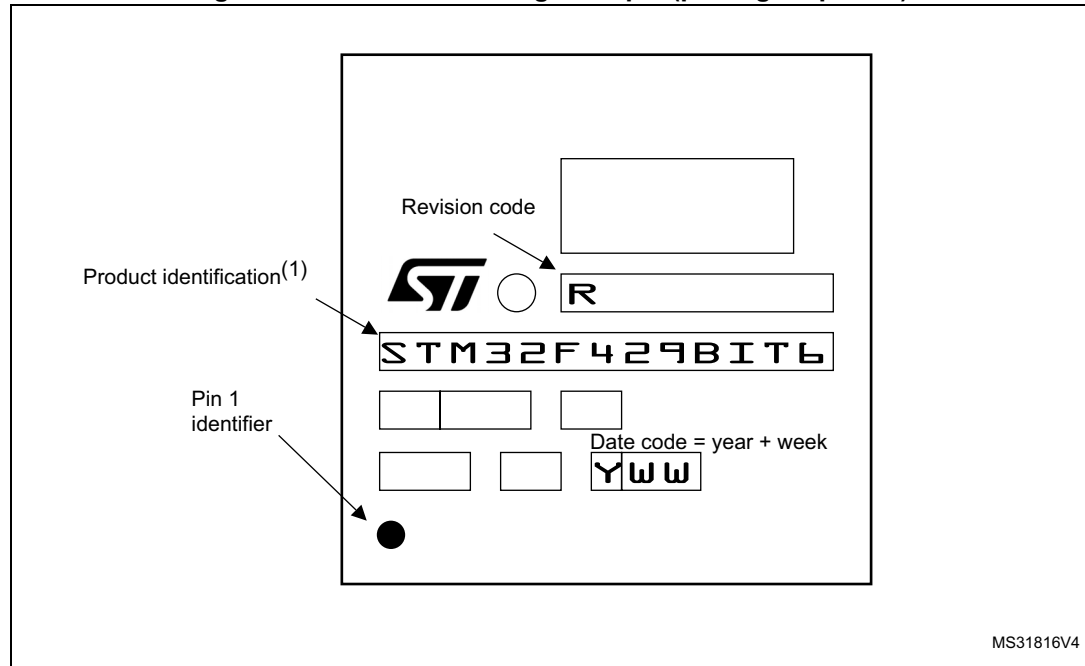
1. Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering Samples to run qualification activity.

### Device marking for LQFP208

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

Other optional marking or inset/upset marks, which depends assembly location, are not indicated below.

**Figure 94. LQFP208 marking example (package top view)**



1. Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering Samples to run qualification activity.

## 9 Revision history

Table 124. Document revision history

Date	Revision	Changes
19-Mar-2013	1	Initial release.
10-Sep-2013	2	<p>Added STM32F429xx part numbers and related informations.  <b>STM32F427xx part numbers:</b>  Replaced FSMC by FMC added Chrom-ART Accelerator and SAI interface.  Increased core, timer, GPIOs, SPI maximum frequencies  Updated <a href="#">Figure 8</a>. Updated <a href="#">Figure 9</a>.  Removed note in <a href="#">Section : Standby mode</a>.  Updated <a href="#">Figure 18</a>.  Updated <a href="#">Table 10: STM32F427xx and STM32F429xx pin and ball definitions</a> and <a href="#">Table 12: STM32F427xx and STM32F429xx alternate function mapping</a>.  Modified <a href="#">Figure 19: Memory map</a>.  Updated <a href="#">Table 17: General operating conditions</a>, <a href="#">Table 18: Limitations depending on the operating power supply range</a>. Removed note 1 in <a href="#">Table 22: reset and power control block characteristics</a>. Added <a href="#">Table 23: Over-drive switching characteristics</a>.  Updated <a href="#">Section : Typical and maximum current consumption</a>, <a href="#">Table 34: Switching output I/O current consumption</a>, <a href="#">Table 35: Peripheral current consumption</a> and <a href="#">Section : On-chip peripheral current consumption</a>.  Updated <a href="#">Table 36: Low-power mode wakeup timings</a>.  Modified <a href="#">Section : High-speed external user clock generated from an external source</a>, <a href="#">Section : Low-speed external user clock generated from an external source</a>, and <a href="#">Section 6.3.10: Internal clock source characteristics</a>.  Updated <a href="#">Table 43: Main PLL characteristics</a> and <a href="#">Table 45: PLLISAI (audio and LCD-TFT PLL) characteristics</a>.  Updated <a href="#">Table 52: EMI characteristics</a>.  Updated <a href="#">Table 57: Output voltage characteristics</a> and <a href="#">Table 58: I/O AC characteristics</a>.  Updated <a href="#">Table 60: TIMx characteristics</a>, <a href="#">Table 61: I<sup>2</sup>C characteristics</a>, <a href="#">Table 62: SPI dynamic characteristics</a>, <a href="#">Section : SAI characteristics</a>.  Updated <a href="#">Table 102: SDRAM read timings</a> and <a href="#">Table 104: SDRAM write timings</a>.</p>

Table 124. Document revision history

Date	Revision	Changes
21-Jan-2016	8	Updated <a href="#">Figure 22: Power supply scheme</a> . Added $t_{d(TXD)}$ values corresponding to $1.71\text{ V} < V_{DD} < 3.6\text{ V}$ in <a href="#">Table 72: Dynamics characteristics: Ethernet MAC signals for RMII</a> .
18-Jul-2016	9	Updated <a href="#">Figure 1: Compatible board design STM32F10xx/STM32F2xx/STM32F4xx for LQFP100 package</a> . Added mission profile compliance with JEDEC JESD47 in <a href="#">Section 6.2: Absolute maximum ratings</a> . Changed <a href="#">Figure 31 HSI deviation versus temperature to ACCHSI versus temperature</a> . Updated $R_{LOAD}$ in <a href="#">Table 85: DAC characteristics</a> . Added note 2. related to the position of the $0.1\text{ }\mu\text{F}$ capacitor below <a href="#">Figure 37: Recommended NRST pin protection</a> . Updated <a href="#">Figure 40: SPI timing diagram - master mode</a> . Added reference to optional marking or inset/upset marks in all package device marking sections. Updated <a href="#">Figure 85: WLCSP143 marking example (package top view)</a> , <a href="#">Figure 88: LQFP144 marking example (package top view)</a> , <a href="#">Figure 91: LQFP176 marking (package top view)</a> , <a href="#">Figure 94: LQFP208 marking example (package top view)</a> . Updated <a href="#">Figure 98: UFBGA176+25 - ball <math>10 \times 10\text{ mm}</math>, <math>0.65\text{ mm}</math> pitch ultra thin fine pitch ball grid array package outline</a> and <a href="#">Table 118: UFBGA176+25 - ball, <math>10 \times 10\text{ mm}</math>, <math>0.65\text{ mm}</math> pitch, ultra fine pitch ball grid array package mechanical data</a> .